

Typical Applications

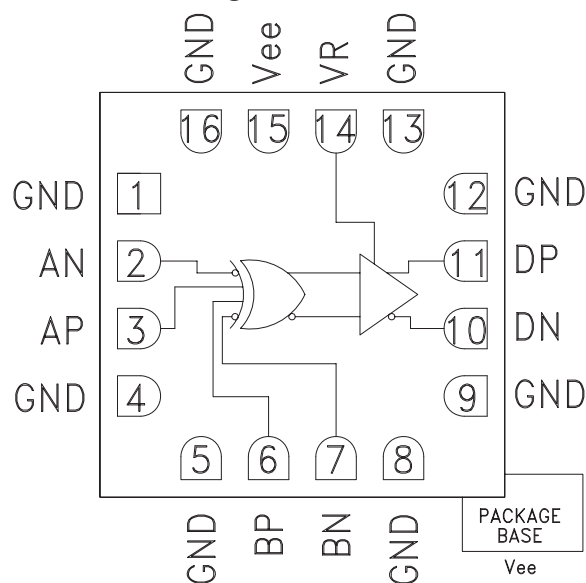
The HMC721LP3E is ideal for:

- 16 G Fiber Channel
- RF ATE Applications
- Broadband Test & Measurement
- Serial Data Transmission up to 14 Gbps
- Digital Logic Systems up to 14 GHz

Features

Inputs Terminated Internally in 50 Ohms
Differential or Single-Ended Operation
Fast Rise and Fall Times: 19 / 18 ps
Low Power Consumption: 230 mW typ.
Programmable Differential Output
Voltage Swing: 600 - 1200 mVp-p
Propagation Delay: 95 ps
Single Supply: -3.3 V
16 Lead 3x3 mm SMT Package: 9 mm²

Functional Diagram



General Description

The HMC721LP3E is a XOR/XNOR gate function designed to support data transmission rates of up to 14 Gbps, and clock frequencies as high as 14 GHz.

All differential inputs to the HMC721LP3E are CML and terminated on-chip with 50 Ohms to the positive supply, GND, and may be DC or AC coupled. Outputs can be connected directly to a 50 Ohm ground-terminated system or drive devices with CML logic input. The HMC721LP3E also features an output level control pin, VR, which allows for loss compensation or signal level optimization. The HMC721LP3E operates from a single -3.3 V supply and is available in ROHS-compliant 3x3 mm SMT package..

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{ee} = -3.3\text{ V}$, $VR = 0\text{ V}$

Parameter	Conditions	Min.	Typ.	Max	Units
Power Supply Voltage		-3.6	-3.3	-3.0	V
Power Supply Current			70		mA
Maximum Data Rate			14		Gbps
Maximum Clock Rate			14		GHz
Input Voltage Range		-1.5		0.5	V
Input Differential Range		0.1		2.0	Vp-p
Input Return Loss	Frequency <14 GHz		10		dB
Output Amplitude	Single-Ended, peak-to-peak		550		mVp-p
	Differential, peak-to-peak		1100		mVp-p
Output High Voltage			-10		mV
Output Low Voltage			-560		mV
Output Rise / Fall Time	Differential, 20% - 80%		19 / 18		ps

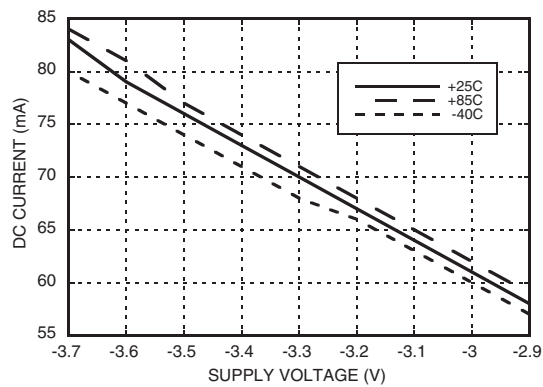
**14 Gbps, FAST RISE TIME XOR / XNOR GATE
w/ PROGRAMMABLE OUTPUT VOLTAGE**

Electrical Specifications (continued)

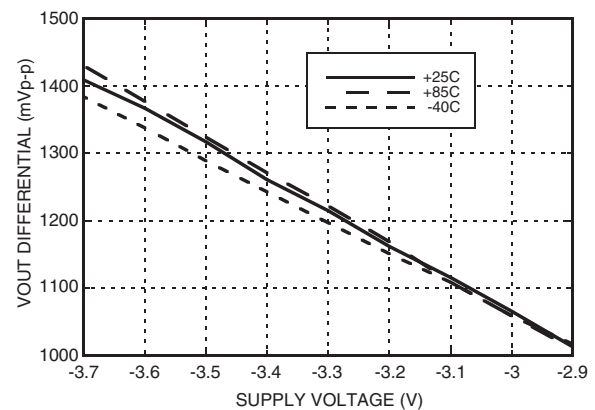
Parameter	Conditions	Min.	Typ.	Max	Units
Output Return Loss	Frequency <13 GHz		10		dB
Small Signal Gain			27		dB
Random Jitter Jr	rms			0.2	ps rms
Deterministic Jitter, Jd	peak-to-peak, 2 ¹⁵ -1 PRBS input [1]		2		ps, pp
Propagation Delay, td			95		ps
VR Pin Current	VR = 0.0 V		2		mA
VR Pin Current	VR = +0.4 V			3.5	mA

[1] Deterministic jitter calculated by simultaneously measuring the jitter of a 300 mV, 13 GHz, 2¹⁵-1 PRBS input, and a single-ended output

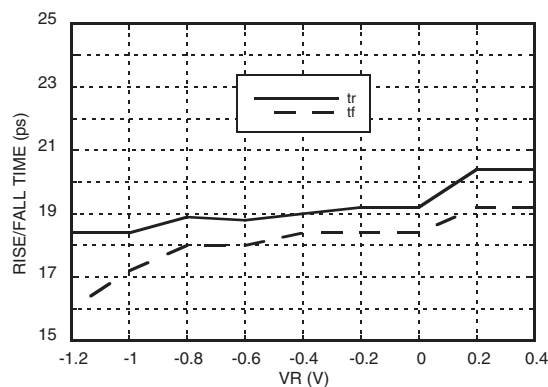
DC Current vs. Supply Voltage [1][2]



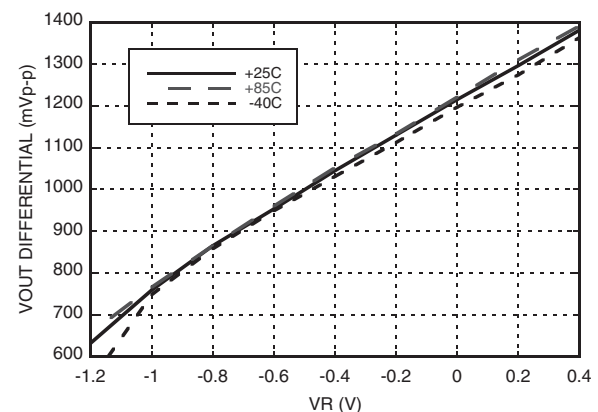
Output Differential Voltage vs. Supply Voltage [1][3]



Rise / Fall Time vs. VR [2][4]



Output Differential Voltage vs. VR [3][4]



[1] VR = 0.0 V

[2] Frequency = 13 GHz

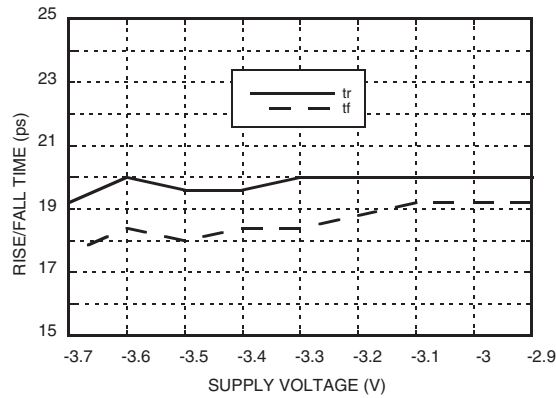
[3] Frequency = 10 GHz

[4] Vee = -3.3 V

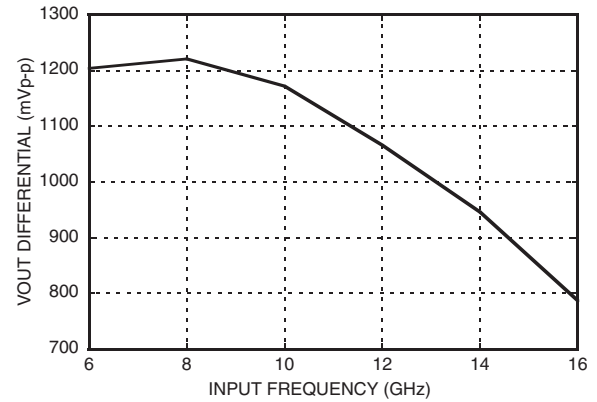


**14 Gbps, FAST RISE TIME XOR / XNOR GATE
w/ PROGRAMMABLE OUTPUT VOLTAGE**

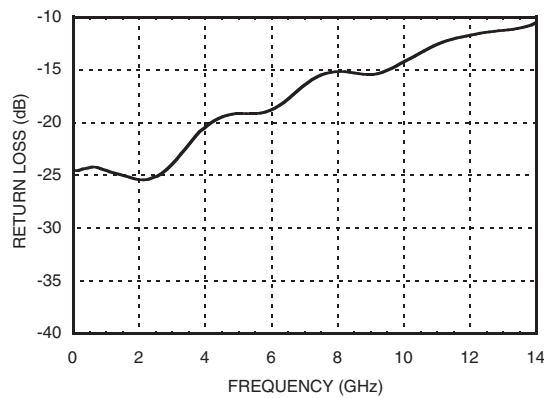
Rise / Fall Time vs. Supply Voltage ^{[1][2]}



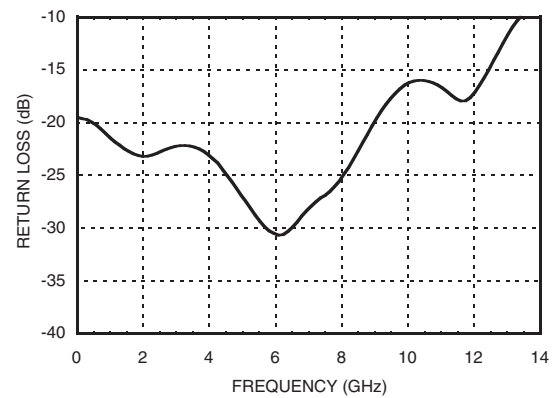
**Output Differential Voltage
vs. Frequency ^{[1][3]}**



Input Return Loss vs. Frequency



Output Return Loss vs. Frequency



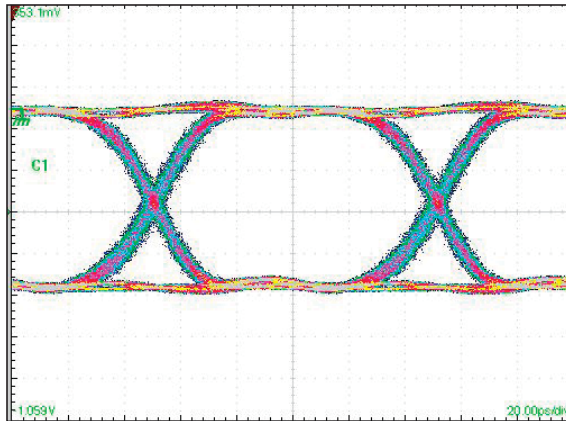
[1] VR = 0.0 V

[2] Frequency = 13 GHz

[3] Vee = -3.3 V

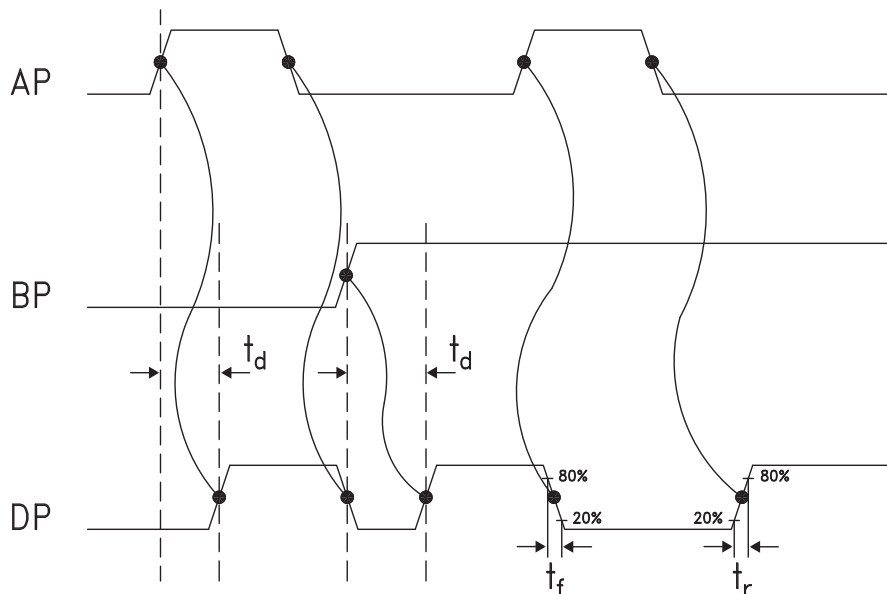
**14 Gbps, FAST RISE TIME XOR / XNOR GATE
w/ PROGRAMMABLE OUTPUT VOLTAGE**

Eye Diagram



[1] Test Conditions:
Waveform generated with an Agilent N4903A J-Bert. Rate = 10 Gbps.
Eye diagram data presented on a Tektronix CSA 8000

Timing Diagram



Truth Table

Input		Outputs
A	B	D
L	L	L
L	H	H
H	L	H
H	H	L
Notes: A = AP - AN B = BP - BN D = DP - DN		H - Positive voltage level L - Negative voltage level

14 Gbps, FAST RISE TIME XOR / XNOR GATE w/ PROGRAMMABLE OUTPUT VOLTAGE

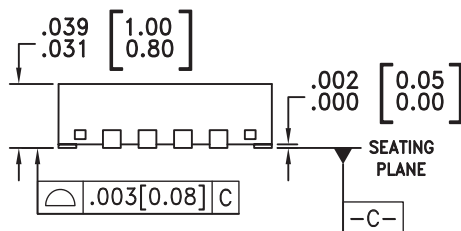
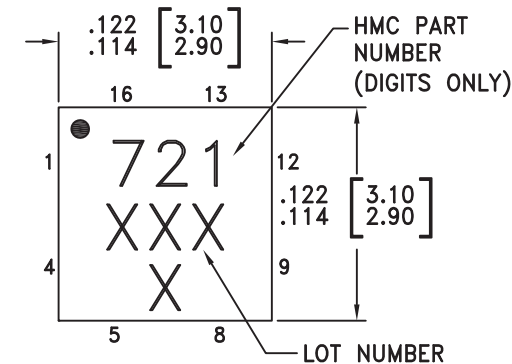
Absolute Maximum Ratings

Power Supply Voltage (Vee)	-3.75 V to +0.5 V
Input Signals	-2 V to +0.5 V
Output Signals	-1.5 V to +1 V
Junction Temperature	125 °C
Continuous Pdiss (T = 85 °C) (derate 20.4 mW/°C above 85 °C)	0.816 W
Thermal Resistance (Rthj-p) Worst case junction to package paddle	49 °C/W
Storage Temperature	-65 °C to +150 °C
Operating Temperature	-40 °C to +85 °C
ESD Sensitivity (HBM)	Class 1A

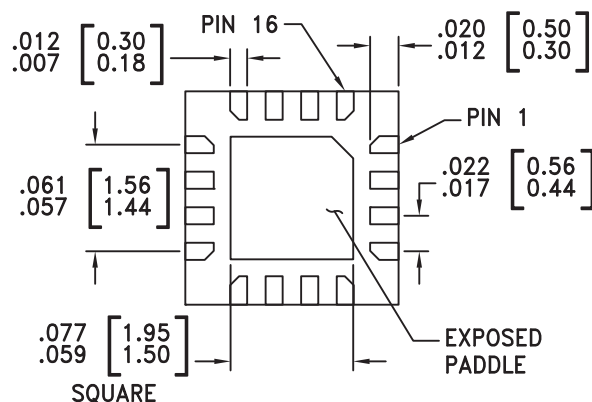


ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



BOTTOM VIEW



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.
8. PADDLE MUST BE SOLDERED TO Vee.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC721LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	721 XXXX

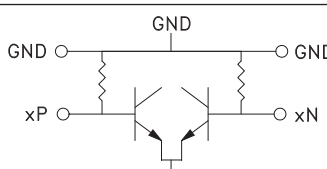
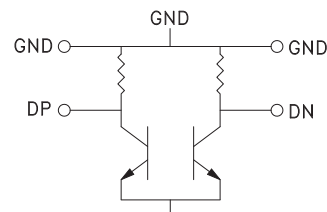
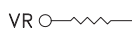
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

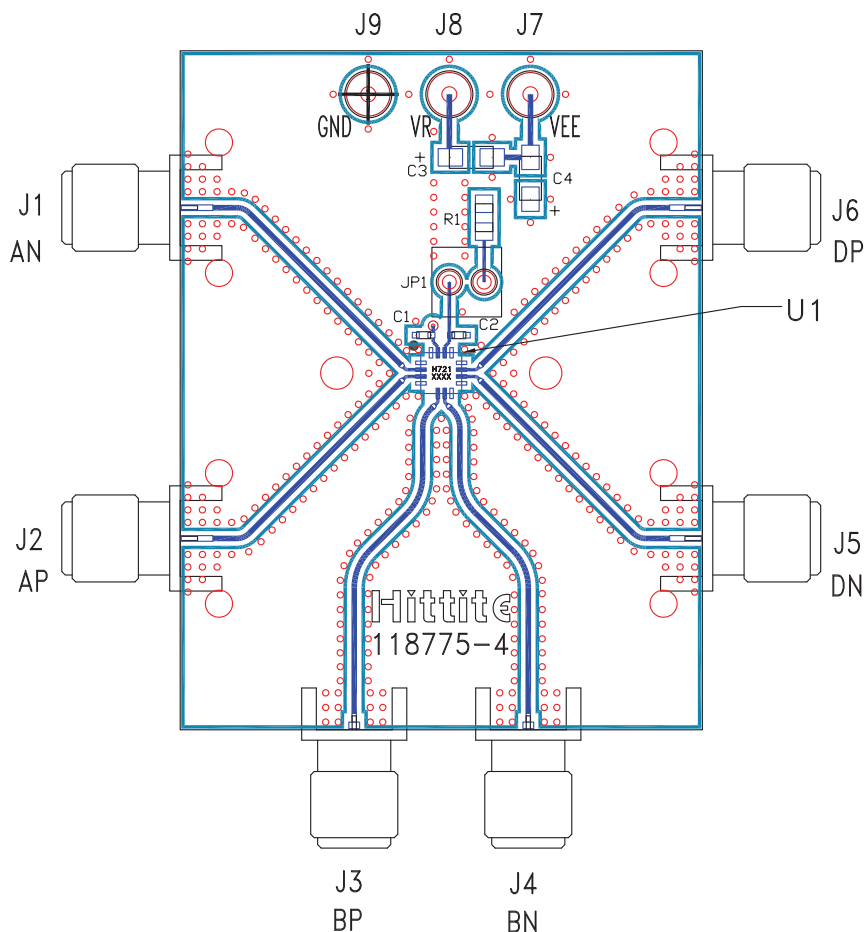
14 Gbps, FAST RISE TIME XOR / XNOR GATE w/ PROGRAMMABLE OUTPUT VOLTAGE

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 4, 5, 8, 9, 12	GND	Signal Grounds	
2, 3 6, 7	AN, AP BP, BN	Differential Clock / Data Inputs: Current Mode Logic (CML) referenced to positive supply	
10, 11	DN, DP	Differential Clock / Data Outputs: Current Mode Logic (CML) referenced to positive supply	
13, 16	GND	Supply Ground	
14	VR	Output level control. Output level may be adjusted by either applying a voltage to VR per "Output Differential vs. VR" plot.	
15, Package Base	Vee	Negative Supply	

14 Gbps, FAST RISE TIME XOR / XNOR GATE w/ PROGRAMMABLE OUTPUT VOLTAGE

Evaluation PCB



List of Materials for Evaluation PCB 118777 [1]

Item	Description
J1 - J6	PCB Mount SMA RF Connectors
J7 - J9	DC Pin
JP1	0.1" Header with Shorting Jumper
C1, C2	100 pF Capacitor, 0402 Pkg.
C3, C4	4.7 μ F Capacitor, Tantalum
R1	10 Ohm Resistor, 0603 Pkg.
U1	HMC721LP3E High Speed Logic, XOR / XNOR
PCB [2]	118775 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

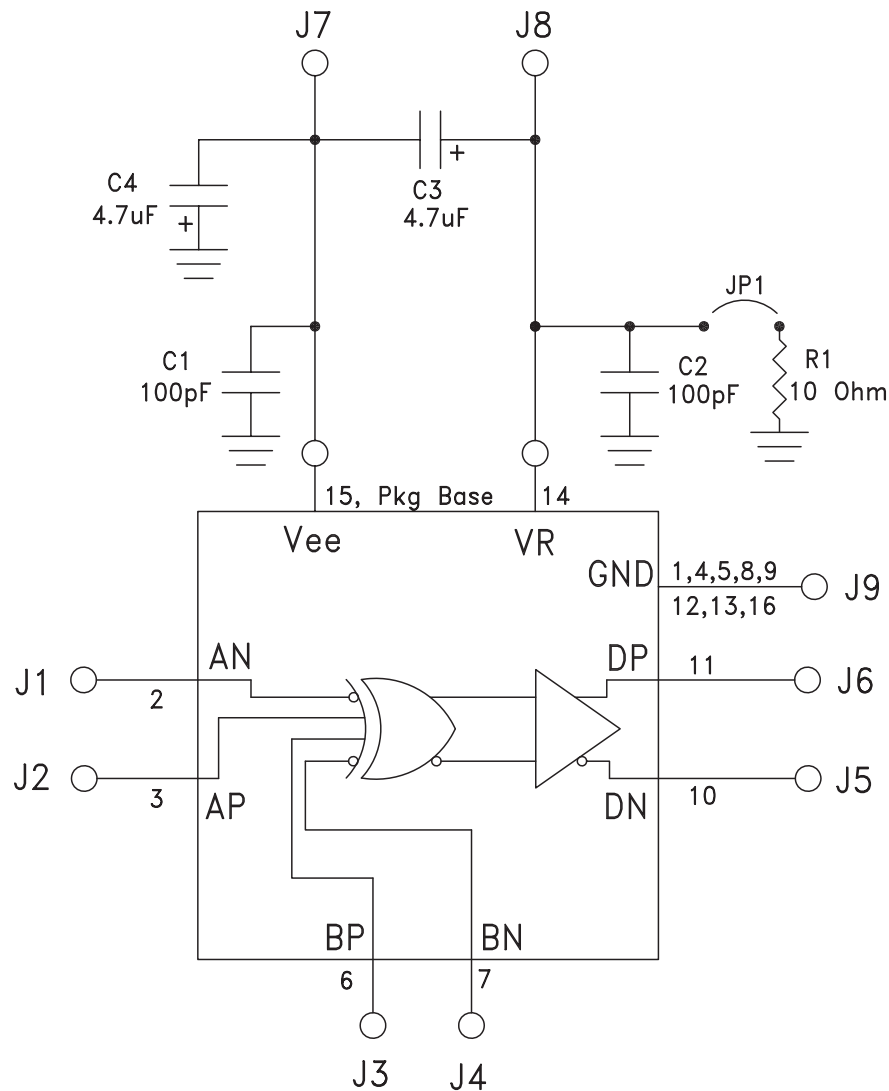
[2] Circuit Board Material: Arlon 25FR or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. The exposed package base should be connected to Vee. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request. Install jumper on JP1 to short VR to GND for normal operation.



**14 Gbps, FAST RISE TIME XOR / XNOR GATE
w/ PROGRAMMABLE OUTPUT VOLTAGE**

Application Circuit



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9